Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal and glass

Overall Length:

Between 1.100 inches and 1.308 inches

Mounting Facility Quantity:

1

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.424 inches and 0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 reverse voltage, peak

Current Rating Per Characteristic:

3.00 amperes forward current, total rms megahertz

Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector blank and 0.5 watts small-signal input power, common-collector universal

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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